

# HITK0203MP

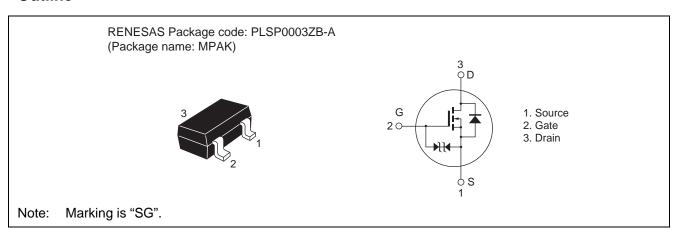
# Silicon N Channel MOS FET Power Switching

R07DS0481EJ0100 Rev.1.00 Jun 22, 2011

#### **Features**

- Low on-resistance
  - $R_{DS(on)}$  = 68 m $\Omega$  typ ( $V_{GS}$  = 4.5 V,  $I_D$  = 1.5 A)
- Low drive current
- High speed switching
- 2.5 V gate drive

#### **Outline**



#### **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to source voltage	V <sub>DSS</sub>	20	V
Gate to source voltage	V <sub>GSS</sub>	±12	V
Drain current	I <sub>D</sub>	2.9	Α
Drain peak current	I <sub>D(pulse)</sub> Note1	10	Α
Body - drain diode reverse drain current	I <sub>DR</sub>	2.9	A
Channel dissipation	Pch Note2	0.8	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW  $\leq$  10  $\mu$ s, duty cycle  $\leq$  1%

2. When using the glass epoxy board (FR-4: 40 x 40 x 1 mm)

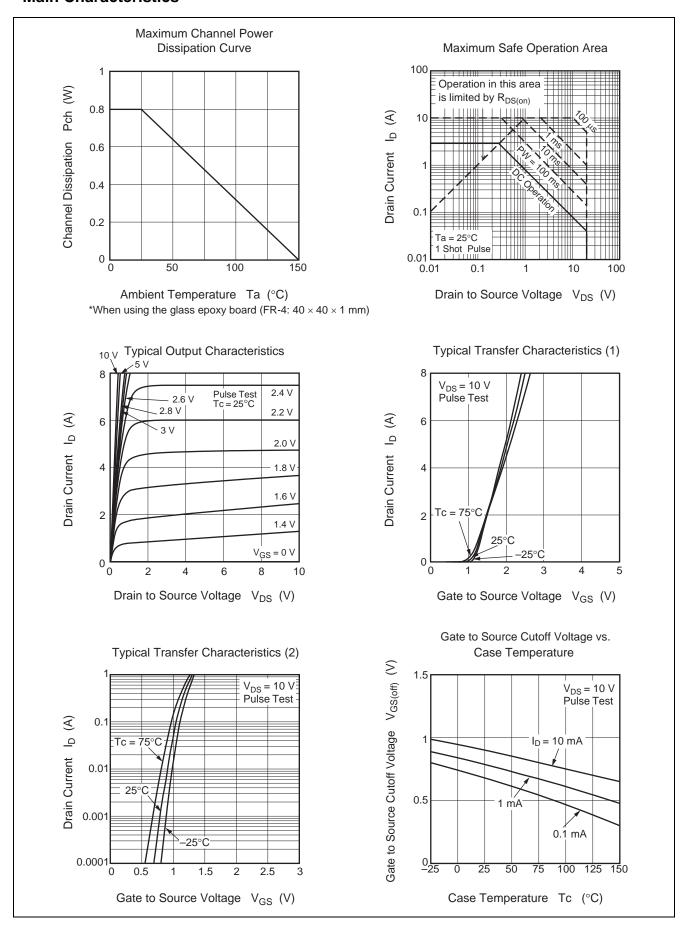
### **Electrical Characteristics**

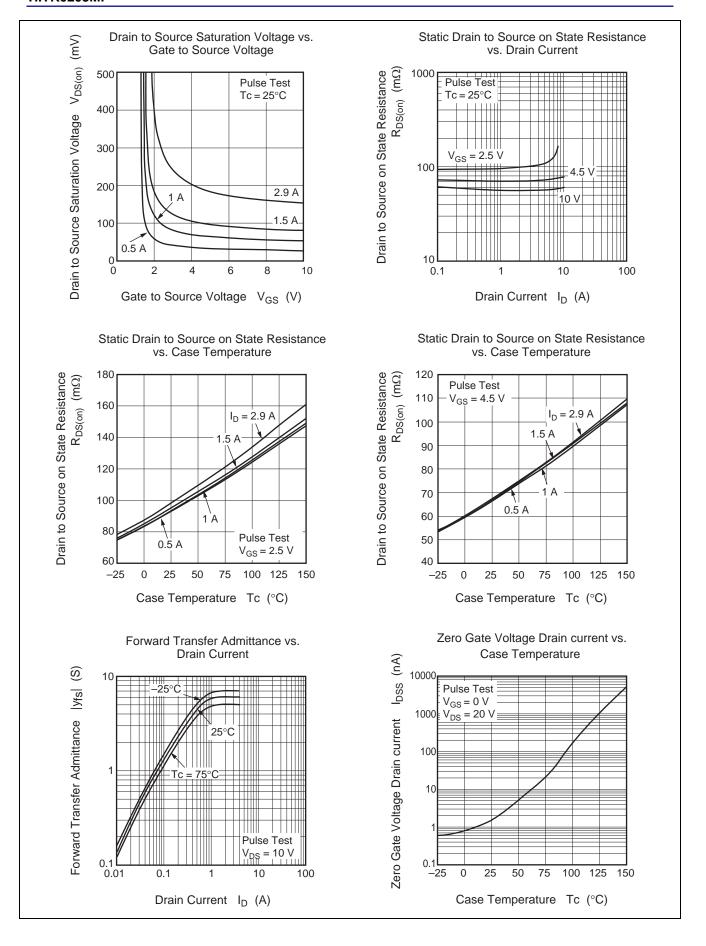
 $(Ta = 25^{\circ}C)$ 

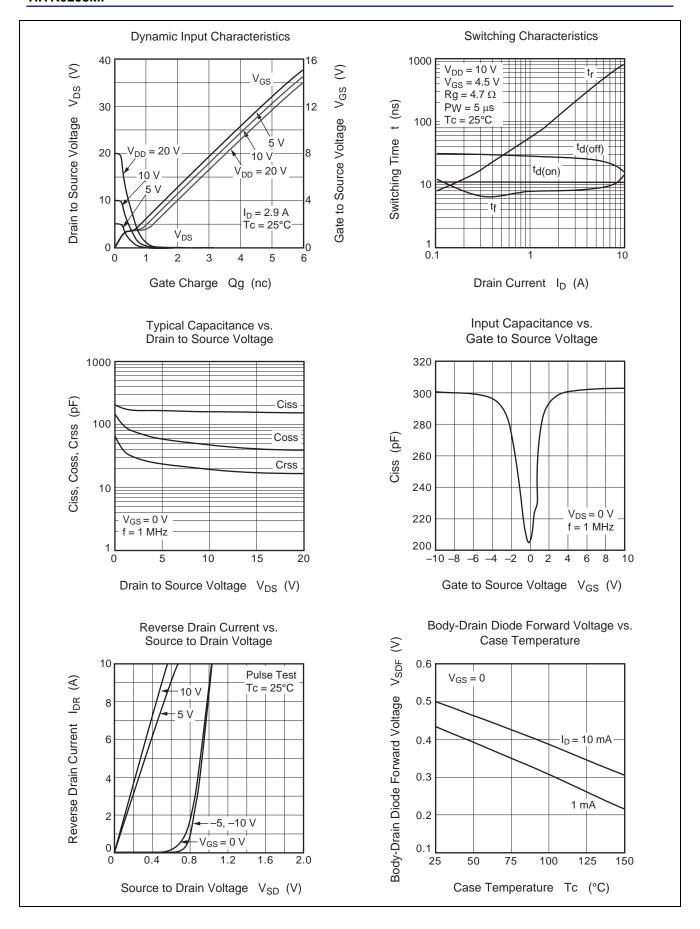
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	20	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±12	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I <sub>GSS</sub>	_	1	±10	μΑ	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$
Drain to source leak current	I <sub>DSS</sub>	_	1	1	μΑ	$V_{DS} = 20 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	0.4	_	1.4	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Drain to source on state resistance	R <sub>DS(on)</sub>	_	68	90	mΩ	$I_D = 1.5 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note3}}$
	R <sub>DS(on)</sub>	_	105	150	mΩ	$I_D = 1.5 \text{ A}, V_{GS} = 2.5 \text{ V}^{\text{Note3}}$
Forward transfer admittance	y <sub>fs</sub>	3.0	5.0	_	S	$I_D = 1.5 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note3}}$
Input capacitance	Ciss	_	159	_	pF	V <sub>DS</sub> = 10 V
Output capacitance	Coss	_	48	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	20	_	pF	f = 1 MHz
Turn - on delay time	t <sub>d(on)</sub>	_	11	_	ns	I <sub>D</sub> = 1.5 A
Rise time	t <sub>r</sub>	_	81	_	ns	V <sub>GS</sub> = 4.5 V
Turn - off delay time	$t_{d(off)}$	_	27	_	ns	$R_L = 6.6 \Omega$
Fall time	t <sub>f</sub>	_	8	_	ns	$Rg = 4.7 \Omega$
Total gate charge	Qg	_	1.9	_	nC	V <sub>DD</sub> = 10 V
Gate to source charge	Qgs		0.4		nC	$V_{GS} = 4.5 \text{ V}$
Gate to drain charge	Qgd		0.5	_	nC	$I_D = 2.9A$
Body - drain diode forward voltage	$V_{DF}$	_	0.85	1.1	V	$I_F = 2.9 \text{ A}, V_{GS} = 0^{\text{Note3}}$

Notes: 3. Pulse test

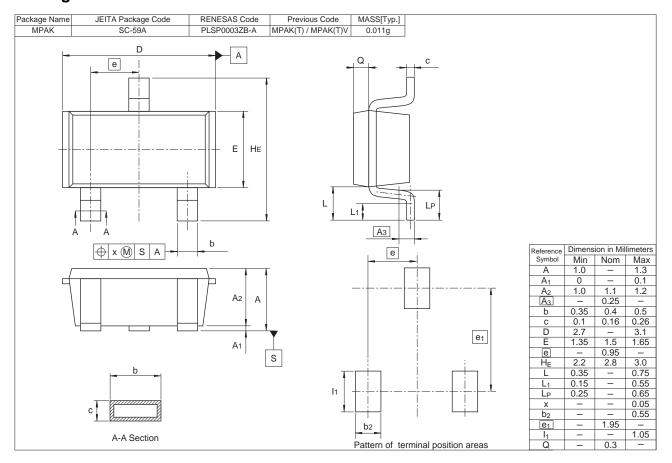
#### **Main Characteristics**







#### **Package Dimensions**



## **Ordering Information**

Orderable Part Number	Quantity	Shipping Container
HITK0203MPTL-HQ	3000 pcs.	φ178 mm reel, 8 mm Emboss taping

Note: This product is designed for consumer use and not for automotive.

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